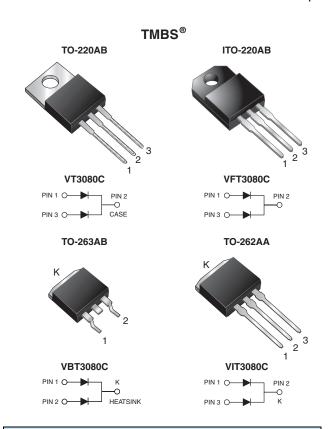
VT3080C-E3, VFT3080C-E3, VBT3080C-E3, VIT3080C-E3

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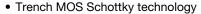
Dual Trench MOS Barrier Schottky Rectifier

Ultra Low $V_F = 0.46 \text{ V}$ at $I_F = 5 \text{ A}$



PRIMARY CHARACTERISTICS							
I _{F(AV)}	2 x 15 A						
V _{RRM}	80 V						
I _{FSM}	150 A						
V _F at I _F = 15 A	0.65 V						
T _J max.	150 °C						
Package	TO-220AB, ITO-220AB, TO-263AB, TO-262AA						
Circuit configuration	Common cathode						

FEATURES





- · Low forward voltage drop, low power losses
- High efficiency operation



RoHS

- Meets MSL level 1, per J-STD-020, LF maximum peak of 245 °C (for TO-263AB package)
- Solder bath temperature 275 °C maximum, 10 s, per JESD 22-B106 (for TO-220AB, ITO-220AB, and TO-262AA package)
- Material categorization: for definitions of compliance please see <u>www.vishav.com/doc?99912</u>

TYPICAL APPLICATIONS

For use in high frequency converters, switching power supplies, freewheeling diodes, OR-ing diode, DC/DC converters and reverse battery protection.

MECHANICAL DATA

Case: TO-220AB, ITO-220AB, TO-263AB and TO-262AA

Molding compound meets UL 94 V-0 flammability rating Base P/N-E3 - RoHS-compliant, commercial grade

Terminals: matte tin plated leads, solderable per J-STD-002 and JESD 22-B102

E3 suffix meets JESD 201 class 1A whisker test

Polarity: as marked

Mounting Torque: 10 in-lbs maximum

MAXIMUM RATINGS (T _A = 25 °C unless otherwise noted)								
PARAMETER			VT3080C	VFT3080C	VBT3080C	VIT3080C	UNIT	
Maximum repetitive peak reverse voltage	V_{RRM}	80						
Maximum average forward rectified current (fig. 1)	per device		30					
Maximum average forward rectified current (fig. 1)	per diode	I _{F(AV)}	15				7 A	
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load per diode		I _{FSM}	150				Α	
Non-repetitive avalanche energy at T _J = 25 °C, L = 60 mH per diode		E _{AS}	160			mJ		
Peak repetitive reverse current at t_p = 2 μ s, 1 kHz, T_J = 38 °C \pm 2 °C per diode		I _{RRM}	1.0			Α		
Isolation voltage (ITO-220AB only) from terminal to heatsink t = 1 min		V _{AC}	1500				V	
Operating junction and storage temperature range		T _J , T _{STG}	-55 to +150				°C	



VT3080C-E3, VFT3080C-E3, VBT3080C-E3, VIT3080C-E3

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ELECTRICAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted)								
PARAMETER	TEST CONDITIONS		SYMBOL	TYP.	MAX.	UNIT		
Instantaneous forward voltage per diode	I _F = 5 A	T _A = 25 °C	V _F ⁽¹⁾	0.52	-	- V		
	I _F = 7.5 A			0.58	-			
	I _F = 15 A			0.75	0.82			
	I _F = 5 A	T _A = 125 °C		0.46	-			
	I _F = 7.5 A			0.52	-			
	I _F = 15 A			0.65	0.70			
Reverse current per diode	V _R = 80 V	T _A = 25 °C T _A = 125 °C	I _R ⁽²⁾	30	700	μΑ		
	v _R = 60 v			20	35	mA		

Notes

 $^{(1)}\,$ Pulse test: 300 μs pulse width, 1 % duty cycle

(2) Pulse test: Pulse width ≤ 40 ms

THERMAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted)							
PARAMETER		SYMBOL	VT3080C	VFT3080C			UNIT
Typical thormal registance	per diode	R _{θJC}	2.5	6.0	2.5	2.5	°C/W
Typical thermal resistance	per device		2.0	5.0	2.0	2.0	

ORDERING INFORMATION (Example)								
PACKAGE	PREFERRED P/N	UNIT WEIGHT (g)	PACKAGE CODE	BASE QUANTITY	DELIVERY MODE			
TO-220AB	VT3080C-E3/4W	1.89	4W	50/tube	Tube			
ITO-220AB	VFT3080C-E3/4W	1.76	4W	50/tube	Tube			
TO-263AB	VBT3080C-E3/4W	1.39	4W	50/tube	Tube			
TO-263AB	VBT3080C-E3/8W	1.39	8W	800/reel	Tape and reel			
TO-262AA	VIT3080C-E3/4W	1.46	4W	50/tube	Tube			

RATINGS AND CHARACTERISTICS CURVES (T_A = 25 °C unless otherwise noted)

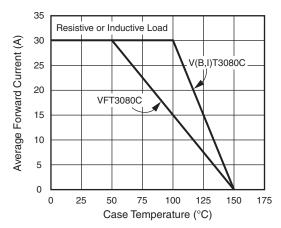


Fig. 1 - Maximum Forward Current Derating Curve

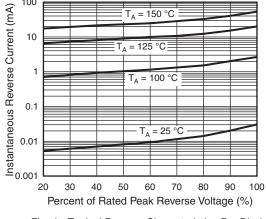


Fig. 4 - Typical Reverse Characteristics Per Diode

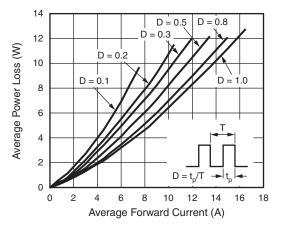


Fig. 2 - Forward Power Loss Characteristics Per Diode

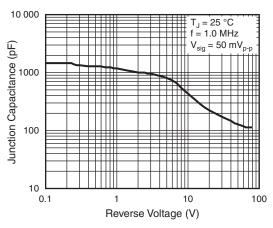


Fig. 5 - Typical Junction Capacitance Per Diode

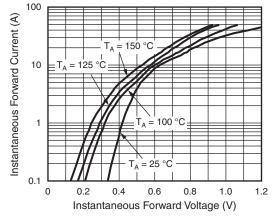


Fig. 3 - Typical Instantaneous Forward Characteristics Per Diode

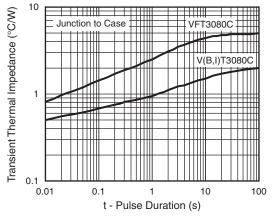


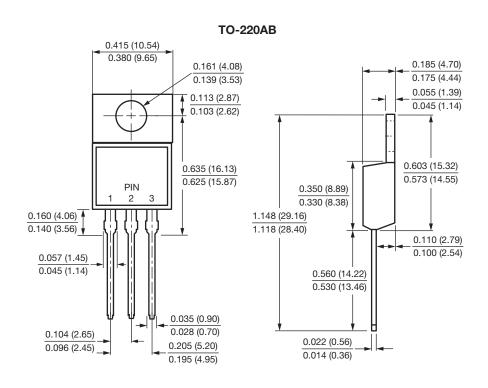
Fig. 6 - Typical Transient Thermal Impedance Per Device

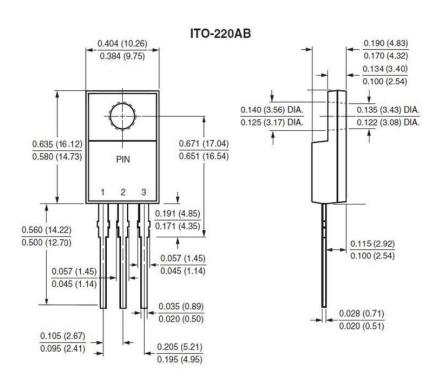


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PACKAGE OUTLINE DIMENSIONS in inches (millimeters)



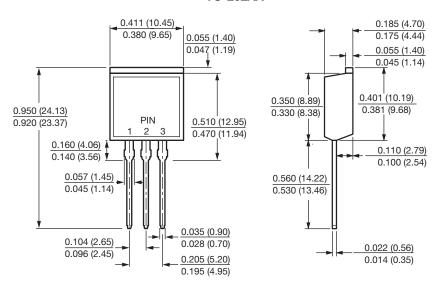


VT3080C-E3, VFT3080C-E3, VBT3080C-E3, VIT3080C-E3

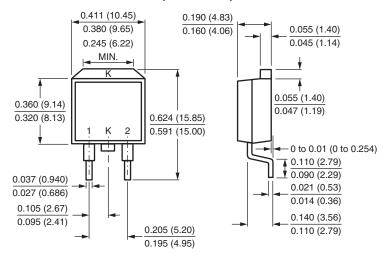
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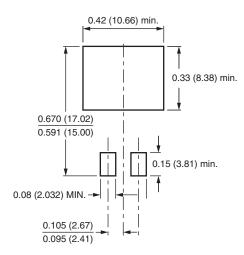
TO-262AA



D²PAK (TO-263AB)



Mounting Pad Layout





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